

A New Anisotropic Dirac Cone Material: A B₂S Honeycomb Monolayer

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ABSTRACT: Different from the isotropic Dirac cones existing in other twodimensional (2D) materials, anisotropic Dirac cones have the merit of anisotropic carrier mobility for applications in direction-dependent quantum devices. Motivated by the recent experimental finding of an anisotropic Dirac cone in borophene, here we report a new 2D anisotropic Dirac cone material, B₂S monolayer, identified by using a global structure search method and first-principles calculation combined with a tight-binding model. The B2S monolayer is found to be stable mechanically, thermally, and dynamically and exhibits an anisotropic Dirac cone exactly at the Fermi level, showing a Fermi velocity of 10⁶ m/s in the same order of magnitude as that of graphene. Moreover, B₂S monolayer is the first anisotropy Dirac cone material with a *pristine* honeycomb structure stabilized by S in free-standing conditions where each atom has four valence electrons on average being isoelectronic to C. This study would expand the Dirac cone material family with new features.



he passion for two-dimensional (2D) Dirac cone materials \mathbf{I} was ignited by graphene,¹ which is characterized by a linear energy dispersion at the Fermi level, exhibiting ballistic charge transport and ultrahigh carrier mobility.² Its Fermi velocity is as high as 0.8×10^6 m/s, only 2 orders of magnitude lower than the velocity of light, offering a new way of developing electronic devices. The fascinating properties and vast applications displayed in graphene have stimulated a growing interest in studying 2D Dirac cone materials. Currently, extensive efforts have been devoted to silicene,³ germanene,⁴ carbon allotropes,^{5–8} boron allotropes,^{9,10} SiC₃,¹¹ C₄N,¹² and Be₃C₂,¹³ which are identified as Dirac materials.

2D boron-based Dirac cone materials have attracted a lot of current attention because boron is positioned on the left side of carbon in the periodic table with a smaller covalent radius and the capacity of flexible bonding. For instance, it has been found that a Dirac cone can exist in a boron β_{12} monolayer¹⁴ that was triangular B chain-based porous sheet,⁷ 8B-Pmmn borophene,¹ etc. Very recently, 2D anisotropic Dirac cones in χ_3 borophene were experimentally discovered by using high-resolution angleresolved photoemission spectroscopy, 1^{17} where the anisotropic Dirac cone exhibits anisotropic carrier mobility that may have advantages in direction-dependent transport for quantum devices. To date for all the reported 2D boron-based Dirac cone materials, their geometries are much more complicated than that of the pristine honeycomb structure of graphene because of the different electronic configuration of the boron atom, which has one fewer electron than carbon. The electrondeficient boron tends to form multiple center bonds in the 2D boron allotropes, where the p_z orbital is not dominating the interactions between electrons, which is different from the situation in graphene. Accordingly, the pristine honeycomb

geometry is unstable for a 2D B sheet in its freestanding state. Although it can be stabilized by adding two electrons to each boron hexagonal ring via doping metal atoms,18,19 in all the metal-stabilized B sheets, metal atoms occupy all the intrinsic hexagonal hollow sites. Thus, the resulting geometries are very different from the simple honeycomb configuration of graphene.

In this work, we chose boron and sulfur for a B-S honeycomb monolayer because of their special electronic configurations and flexible bonding ability.^{20–31} In addition, a binary compound with an atomic ratio greater than 1 could generate crystals with low symmetry compared with graphene³² and might lead to the materials with anisotropic Dirac cones, thus providing Fermi velocities in practical devices that are more flexible and tunable than those of the isotropic Dirac cone.^{33–36} On the basis of the global structure search and stateof-the-art theoretical simulations, we have identified a desirable B₂S honeycomb monolayer with an anisotropic Dirac cone located at the high symmetric line in k-space. In this structure, each atom has four valence electrons on average making B₂S isoeletronic to graphene, while the lower symmetry induced by the two different species of elements is responsible for the anisotropic Dirac cone.

Computational Methods. The ground-state structure of 2D B₂S is predicted by using the particle swarm optimization (PSO) algorithm implemented in the CALYPSO package.³⁷⁻⁴² The population size and the number of generations are both set to 30 to ensure the convergence. The number of formula units per unit cell are set to be 1, 2, 3, and 4, corresponding to B_2S_2 ,

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 B_4S_2 , B_6S_3 , and B_8S_4 , respectively. To accommodate the structure buckling, we set the buffering thickness to 0.1 Å.37 Atomic structure optimization, total energy, and electronic structure calculations are performed based on density functional theory (DFT), as implemented in the Vienna ab initio simulation package (VASP).⁴³ The projector augmented wave (PAW) method⁴⁴ is employed to treat the interactions between ion cores and valence electrons with a kinetic energy cutoff of 450 eV. The first Brillouin zone is sampled by a $6 \times 10 \times 1$ kpoint grid within the Monkhorst-Pack scheme.⁴⁵ The exchange-correlation potential is treated using the Perdew-Burke-Ernzerh (PBE) functional⁴⁶ within the generalized gradient approximation $(GGA)^{47}$ in most cases, while the HSE06^{48,49} hybrid functional is used to obtain a more accurate electronic band structure. The atomic positons are fully relaxed until the energy and atomic forces converge to 10^{-4} eV and 10^{-2} eV/Å, respectively. A large vacuum space of 20 Å in the perpendicular direction of the sheet is used to avoid the interactions between periodic images. The finite displacement method implemented in the phonopy package⁵⁰ is used to calculate the phonon spectra. Ab initio molecular dynamics (AIMD) simulations are carried out to confirm the thermal stability. The tight-binding (TB) matrix elements are calculated by projecting Bloch states onto the maximally localized Wannier functions (MLWFs), using the Wannier90 package⁵ interfaced with Quantum ESPRESSO.52

Through the global structure searching for a B_2S monolayer sheet, we obtain three energetically favorable monolayer B_2S phases. The optimized geometries and the relative energies with respect to the lowest energy (0 eV) are plotted in Figure 1a-c. All of them present a graphene-like honeycomb structure



Figure 1. (a–c) Optimized low-lying energy geometries and (d) a slice (crossing the monatomic thick structure) of the electron localization function (ELF) of the B_2S monolayer.

without any buckling. The structure shown in Figure 1a is identified to be the most stable atomic configuration of the B₂S monolayer; the configuration shown in Figure 1a is 0.06 and 0.16 eV per B₂S formula unit lower in energy than the one shown in panels b and c of Figure 1, respectively. This structure has an orthogonal primitive cell (space group PBAM with a point group D_{2h}) containing four formula units, with optimized lattice constants of a = 9.14 Å, b = 5.26 Å, and c = 20.88 Å. All of the boron and sulfur atoms are three-coordinated, making it possible for their p_z orbitals to be conjugated. The hexagonal rings in the B₂S sheet are distorted with the bond angles ranging from 114° to 123° because B and S atoms have

different covalent radii and electronegativities. The bond lengths of B–B and B–S are 1.62 and 1.82 Å, respectively. This deviation from ideal honeycomb structure finally contributes to the anisotropic properties of this material, such as mechanical and electric properties.

To get more insight into the chemical bonding of the B_2S monolayer, we calculate its electron localization function $(ELF)^{53}$ to analyze the electron distribution. The ELF is a useful tool for chemical bond classification, which can be described in the form of a contour plot in real space with values renormalized between 0.00 and 1.00. The values of 1.00 and 0.50 correspond to fully localized and fully delocalized electrons, respectively, while the value 0.00 refers to very low charge density. The calculated results are plotted in Figure 1d, where the region with a large ELF value is portrayed in red, showing the paired electrons states of the σ bond formed by the sp²-hybridized orbitals of B and S atoms.

To examine the stability of the B₂S monolayer, we first calculate its cohesive energy, which is defined by $E_{\rm coh} = -(E_{\rm B_2S} - 8E_{\rm B} - 4E_{\rm S})/12$, where $E_{\rm B}$ and $E_{\rm S}$ are the total energies of a single B atom and single S atom, respectively, and $E_{\rm B_2S}$ is the total energy of a B₂S unit cell. Our calculated value is 5.3 eV/ atom, which is comparable to that of some bulk boron sulfide phases recorded in the materials project data set,⁵⁴ including B₁₂S (5.8 eV/atom), B₂S₃ (4.9 eV/atom), and BS₂ (4.6 eV/ atom), indicating that the B₂S sheet is energetically favorable. These cohesive energies are calculated at the same theoretical level.

We then examine the thermal stability of the B_2S sheet by performing AIMD simulations. A 2 × 3 × 1 supercell containing 72 atoms is adopted to reduce the constraint of the periodic boundary condition. The simulation is carried out with a Nosé–Hoover heat bath scheme⁵⁵ at 1000 K for 10 ps with a time step of 1 fs. The fluctuation of the total potential energy with simulation time is plotted in Figure 2b, which shows that the average value of the total potential energy remains nearly constant during the entire simulation. The structure of the B_2S monolayer at the end of the simulation is also plotted in Figure 2a, with no obvious structure collapse appearing. The above results indicate that the B_2S monolayer has good thermal stability and can maintain its structural integrity up to 1000 K. Therefore, this monolayer is thermally stable enough to withstand relatively high temperatures.

We also calculate the phonon spectra to check the dynamical stability of the B₂S monolayer. The calculated phonon dispersion curves are displayed in Figure 2b. The absence of an imaginary mode in the entire Brillouin zone confirms that the B₂S sheet is dynamically stable. Additionally, we further examine the mechanical stability of B₂S by calculating its linear elastic constants. The 2D linear elastic constants are calculated to be $C_{11} = 150 \text{ N} \cdot \text{m}^{-1}$, $C_{22} = 160 \text{ N} \cdot \text{m}^{-1}$, $C_{12} = 32 \text{ N} \cdot \text{m}^{-1}$, and $C_{44} = 60 \text{ N} \cdot \text{m}^{-1}$. The stability criteria for an orthorhombic 2D system are⁵⁶

$$C_{11} > 0; C_{22} > 0; C_{44} > 0$$

$$C_{11}C_{22} > C_{12}^{2}$$

It is obvious that the elastic constants of the B_2S monolayer satisfy those conditions, confirming the mechanical stability of the sheet. Moreover, the in-plane Young's modulus and Poisson



Figure 2. (a) Phonon spectra of the B_2S monolayer. (b) Fluctuation of total potential energy of B_2S monolayer during the AIMD simulation at 1000 K. The inset is the structure of B_2S at the end of the AIMD simulation.

ratio along an arbitrary direction θ (θ is the angle relative to the positive *x* direction in the sheet) can be expressed as⁵⁷

$$E(\theta) = \frac{C_{11}C_{22} - C_{12}^{2}}{C_{11}s^{4} + C_{22}c^{4} + \left(\frac{C_{11}C_{22} - C_{12}^{2}}{C_{44}} - 2C_{12}\right)c^{2}s^{2}}$$
$$\nu(\theta) = -\frac{\left(C_{11} + C_{22} - \frac{C_{11}C_{22} - C_{12}^{2}}{C_{44}}\right)c^{2}s^{2} - C_{12}(c^{4} + s^{4})}{C_{11}s^{4} + C_{22}c^{4} + \left(\frac{C_{11}C_{22} - C_{12}^{2}}{C_{44}} - 2C_{12}\right)c^{2}s^{2}}$$

where $c = \cos \theta$ and $s = \sin \theta$. For the B₂S monolayer, the calculated $E(\theta)$ and $\nu(\theta)$ are depicted in the polar diagrams in Figure 3. The diagrams show that both the Young's modulus



Figure 3. Polar diagrams for the (a) Young's modulus and (b) Poisson ratio of the B_2S monolayer.

and Poisson ratio are anisotropic. The lowest Young's modulus is 143 $N \cdot m^{-1}$, which is much larger than that of silicene⁵⁸ (62 $N \cdot m^{-1}$) and MoS₂ monolayer (129 $N \cdot m^{-1}$),⁵⁹ confirming the strong bonding in the flat monolayered B₂S sheet. This anisotropic characteristic originates from the unique arrangement of the boron and sulfur atoms in this sheet, which affects not only its mechanical properties but also its electronic properties.

After confirming the structure stability of the B_2S monolayer, we calculate its electronic band structures and density of states (DOS) to explore the electronic properties. As presented in Figure 4a, the PBE results show that there are two bands crossing each other linearly at the Fermi level, indicating the existence of a zero-gap Dirac cone. To confirm the result, we use the HSE06 functional to obtain more accurate band structures; as shown in Figure 4a, the Dirac cone still exists. We further study the effect of spin-orbit coupling (SOC) on the electronic structure of B_2S . The SOC effect is so small that no observable band gap occurred because both B and S are light elements. To get insight into the formation of the zero-energy-gap state, we analyze the symmetry of the B_2S monolayer. We find that the monolayer possesses space and time reversion symmetry and obeys the even-atom-number rule as most Dirac materials,⁶⁰ which leads to a constrained Hamiltonian and makes it possible to achieve a Dirac cone in this 2D system.

In particular, the Dirac cone has different slopes along the k_x and k_y directions, which means that the Dirac Fermions transport with different velocities in different directions.⁶¹ To get a more clear observation of the anisotropic Dirac cone, we calculate the three-dimensional (3D) band structures of the B₂S monolayer. The results displayed in Figure 5a,b show the presence of a distorted Dirac cone, implying direction-dependent Fermi velocities in this sheet. By a linear fitting of the band, we obtain the Fermi velocity ($V_f = \partial E/\partial(\hbar k)$ of the Dirac Fermions in B₂S. The Fermi velocity is 6.7×10^5 m/s along the k_x direction and 4.8×10^5 m/s along the k_y direction, which is comparable to that of graphene (8.0×10^5 m/s). Both the high and direction-dependent Fermi velocities imply the great potential for direction-dependent quantum information devices.

To explore the origin of the Dirac point, we calculate the projected density of states (PDOS) (Figure 4b), atomdecomposed (Figure 6a,b), and orbital-decomposed (Figure 6c-f) band structures of the B_2S monolayer. The orbitaldecomposed and atom-decomposed band structures clearly show that the bands near the Fermi level originate from the p_z orbitals. Therefore, it is possible to model the Dirac cone structure using a simple TB Hamiltonian for these p_z orbitals.

By using the WANNIER90 package, we can describe the electronic structure of B₂S in terms of the maximally localized Wannier functions (MLWFs) instead of the extended Bloch functions. The tight-binding Hamiltonian for the B₂S monolayer in a MLWF basis set is modeled as $\hat{H} = \sum_i \varepsilon_i \hat{c}_i^{\dagger} \hat{c}_i + \sum_{i \neq j} t_{ij} c_i^{\dagger} c_j$, where ε_i is the on-site energy, t_{ij} the hopping integral, and $c_i^{\dagger} c_j$ the Fermion creation and annihilation operators at site *i*. We consider only the p_z orbitals in our TB model because the dominant contributions to the Dirac cone are from the p_z orbitals of B and S atoms, as shown in Figure 6.



Figure 4. (a) Electronic band structure calculated by using the PBE (blue lines) and HSE06 (red dashed lines) functional. (b) Density of states (DOS) and projected DOS calculated at the PBE level. (c) Brillouin Zone and the high-symmetry path of the B_2S monolayer.



Figure 5. 3D electronic band structure of B₂S near the Fermi level calculated by using the PBE functional.



Figure 6. (a and b) Atom-decomposed band structures calculated by PBE functional. (c-f) Orbital-decomposed band structures calculated by PBE functional.

Including all the hoppings with hopping integral greater than 10^{-6} , a relatively accurate band structure is obtained, which is in good agreement with that of the calculations at the PBE level,

as shown in Figure 7a. We then analyze the onsite-energies and hopping integrals between the different p_z orbitals obtained



Figure 7. (a) Band structure calculated by using the TB model and PBE functional. (b) Hopping integral parameters of the B_2S monolayer.

using the TB model. The onsite energy is the energy of an electron sitting in a specific orbital in the presence of its neighboring atoms, whereas the hopping energies are proportional to the frequency of the electron jumping from one state to another. As shown in Figure 7b, there are two kinds of chemical environments of B atom and one chemical environment of S atom in the B_2S monolayer, denoted as B_1 , B_2 , and S_1 , respectively.

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The onsite energy of a S atom is 6.4 eV, while that for a B atom is 5.4 eV, which means that the S atoms are more likely to attract electrons. This is also confirmed by the Bader charge analysis.⁶² It is found that the S atom gains 1.3 electrons, while the B atom loses 0.65 electrons on average. These results are consistent with the experiential view in chemistry that sulfur has a larger electronegativity than boron. An analysis of the hopping energies obtained using our TB model reveals there are two major hopping parameters, denoted as t_1 and t_2 in Figure 7b. The value of t_2 (1.7) is larger than that of t_1 (0.8), because the p_z orbitals of B_2 and B_1 match each other better, resulting in greater orbital overlap between them. This analysis also uncovers the reason for the anisotropic Dirac cone, which is due to the different electron-transfer abilities between these neighboring atoms that breaks the particle-hole symmetry in the B₂S monolayer, resulting in an anisotropic Dirac cone.⁶

In summary, by using the PSO-based global structure search method and first-principles calculations with a tight binding model, we have identified a novel B2S monolayer, which is stable dynamically, thermally, and mechanically. The geometry of the B₂S monolayer is very intriguing because B has one electron less than C, the graphene geometry is unstable for a pure B sheet, which can be stabilized by S leading to a honeycomb structure similar to that of graphene, silicene, germanene, and stanene. However, the B₂S monolayer is electronically different from these honeycomb sheets, showing an anisotropic Dirac cone along the high-symmetry path with anisotropic Fermi velocities in the same order of magnitude compared with that of graphene, thus exhibiting great potential for B₂S to be applied in direction-dependent electronic devices with high speed and low dissipation. We hope this study stimulates experimental efforts to synthesize the predicted new honeycomb monolayer to enrich the anisotropic Dirac cone materials.

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Notes

The authors declare no competing financial interest.

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